## NSN 5962-01-261-4049

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Body Length:
0.640 inches
Body Width:
0.420 inches
Body Height:
0.090 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and bipolar and programmable
Inclosure Material:
Metal or ceramic or plastic
Inclosure Configuration:
Flat pack
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
F-6 mil-m-38510
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

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